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TRANSMITTAL FORM

(to be used for all correspondence after initial filing)

Application Number	10/666,025 (U.S. Pat. No. 7,033,642)
Filing Date	September 17, 2003 (Iss'd April 25, 2006)
First Named Inventor	Cem Basceri
Art Unit	1762
Examiner Name	David P. Turocy
Attorney Docket Number	MI22-2407
Total Number of Pages in This Submission	6

ENCLOSURES (Check all that apply)

<input type="checkbox"/> Fee Transmittal Form <input type="checkbox"/> Fee Attached <input type="checkbox"/> Amendment/Reply <input type="checkbox"/> After Final <input type="checkbox"/> Affidavits/declaration(s) <input type="checkbox"/> Extension of Time Request <input type="checkbox"/> Express Abandonment Request <input type="checkbox"/> Information Disclosure Statement <input type="checkbox"/> Certified Copy of Priority Document(s) <input type="checkbox"/> Reply to Missing Parts/ Incomplete Application <input type="checkbox"/> Reply to Missing Parts under 37 CFR 1.52 or 1.53	<input type="checkbox"/> Drawing(s) <input type="checkbox"/> Licensing-related Papers <input type="checkbox"/> Petition <input type="checkbox"/> Petition to Convert to a Provisional Application <input type="checkbox"/> Power of Attorney, Revocation <input type="checkbox"/> Change of Correspondence Address <input type="checkbox"/> Terminal Disclaimer <input type="checkbox"/> Request for Refund <input type="checkbox"/> CD, Number of CD(s) _____ <input type="checkbox"/> Landscape Table on CD	<input type="checkbox"/> After Allowance Communication to TC <input type="checkbox"/> Appeal Communication to Board of Appeals and Interferences <input type="checkbox"/> Appeal Communication to TC (Appeal Notice, Brief, Reply Brief) <input type="checkbox"/> Proprietary Information <input type="checkbox"/> Status Letter <input checked="" type="checkbox"/> Other Enclosure(s) (please identify below): PTO Return Receipt Postcard; Request for Certificate of Correction - PTO mistake; Certificate of Correction in duplicate
Remarks Customer No. 021567 No filing fee is required with this filing. However, in the event that a fee is required for filing this Certificate of Correction, please charge such fee to Deposit Account No. 23-0925.		

SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT

Firm Name	Wells St. John P.S.		
Signature			
Printed name	Mark S. Matkin		
Date	February 9, 2007	Reg. No.	32,268

Certificate of Correction
FEB 16 2007

CERTIFICATE OF TRANSMISSION/MAILING

I hereby certify that this correspondence is being facsimile transmitted to the USPTO or deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on the date shown below:

Signature			
Typed or printed name	Elizabeth Weber	Date	February 9, 2007

This collection of information is required by 37 CFR 1.5. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.11 and 1.14. This collection is estimated to 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.

FEB 16 2007



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent No.7,033,642 B2
Patent Issue DateApril 25, 2006
Application Serial No.10/666,025
Filing Date September 17, 2003
Assignee Micron Technology, Inc.
Inventorship Cem Basceri
Attorney's Docket No.MI22-2407
Title: Plasma Enhanced Chemical Vapor Deposition Method of Forming A
Titanium Silicide Comprising Layer

REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT
FOR PTO MISTAKES (37 C.F.R. 1.322(a))

To: Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450
ATTN: Decision and Certificate of Correction
Branch of the Patent Issue Division

From: Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)
Wells St. John P.S.
601 W. First Avenue, Suite 1300
Spokane, WA 99201-3828

Sir:

It is hereby requested that a Certificate of Correction be issued with respect to Patent No. 7,033,642 B2, granted April 25, 2006, in accordance with the Certificate of Correction form attached hereto in duplicate.

The errors listed on the Certificate of Correction form were apparently incurred through the fault of the PTO as will be disclosed by the records of files in the Office.

Since this Certificate of Correction is being requested due to PTO errors, it is believed that no fee is due. However, in the event that a fee is required for issuance of this Certificate of Correction, please charge the fee specified under

FEB 16 2007


37 C.F.R. § 1.20(a) to Deposit Account No. 23-0925. Please credit Deposit Account No. 23-0925 with any overpayment of the above fee.

Attached hereto, in duplicate is Form PTO-1050, with at least one copy being suitable for printing.

Respectfully submitted,

Dated: 2-9-07

By:


Mark S. Matkin
Reg. No. 32,268

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,033,642 B2

APPLICATION NO.: 10/666,025

ISSUE DATE : April 25, 2006

INVENTOR(S) : Cem Basceri

It is certified that an error or errors appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Col. 2, line 9 –

Replace “titanium suicide depositions on separate wafers. For”

Insert --titanium silicide depositions on separate wafers. For--

Col. 2, line 50 –

Replace “of forming titanium suicide comprising layers on”

Insert --of forming titanium silicide comprising layers on--

Col. 4, line 41 –

Replace “to plasma enhance chemical vapor deposit a titanium suicide”

Insert --to plasma enhance chemical vapor deposit a titanium silicide--

Page
1 of 2

Mailing Address of Sender:

Mark S. Matkin
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601 West First Avenue, Suite 1300
Spokane, WA 99201-3828

Patent No. US 7,033,642 B2

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UNITED STATES PATENT AND TRADEMARK OFFICE
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APPLICATION NO.: 10/666,025

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Col. 4, line 55 –

Replace "SiH₄ at from 0.5 sccm to 10 sccm, TiCl₄ at from 50 sccm to"

Insert --SiH₄ at from 0.5 sccm to 10 sccm, TiCl₄ at from 50 sccm to--

Col 4, line 60 –

Replace "vapor deposit a titanium suicide comprising layer which"

Insert --vapor deposit a titanium silicide comprising layer which--

Page
2 of 2

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